



NPN AND PNP HIGH VOLTAGE TRANSISTOR

Voltage

60~80V

Power

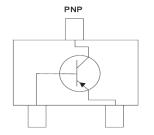
225mW

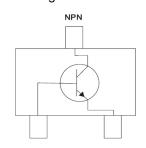
Features

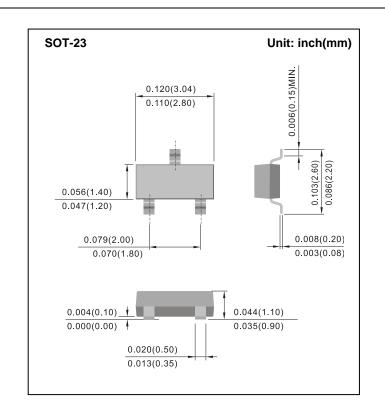
- NPN and PNP silicon, planar design
- Collector current I_C = 500mA
- Lead free in compliance with EU RoHS2.0 (2011/65/EU & 2015/865/EU directive)
- Green molding compound as per IEC61249 Std.. (Halogen Free)

Mechanical Data

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams







Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

| PARAMETER | SYMBOL | MMBTA05 | MMBTA55 | MMBTA06 | MMBTA56 | UNITS |
|------------------------------|------------------|---------|---------|---------|---------|-------|
| Marking | | B05 | B55 | B06 | B56 | |
| Collector-Emitter Voltage | V _{CEO} | 60 | | 80 | | V |
| Collector-Base Voltage | V _{CEO} | 60 | | 80 | | V |
| Emitter-Base Voltage | V_{EBO} | 4 | | | V | |
| Collector Current-Continuous | I _C | 500 | | | mA | |
| Circuit Figure | | NPN | PNP | NPN | PNP | |

Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

| CHARACTERISTIC | SYMBOL | MAX. | UNITS |
|--|-------------------|------------|-------|
| Total device dissipation FR-4 board (Note 1) T _A =25°C | Б | 225 | mW |
| derate above 25°C | P_{D} | 1.8 | mW/°C |
| Typical thermal resistance | $R_{	heta JA}$ | 556 | °C/W |
| Total device dissipation alumina substrate (Note 2) T _A =25°C | | 300 | mW |
| derate above 25°C | P_{D} | 2.4 | mW/°C |
| Typical thermal resistance | $R_{\theta JA}$ | 417 | °C/W |
| Operating junction and storage temperature range | T_J , T_{STG} | -55 to 150 | °C |

Note: 1. FR-4=70 x 60 x 1mm.

2. Alumina=0.4 x 0.3 x 0.024 in. 99.5 alumina.



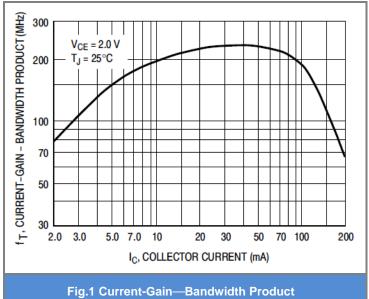


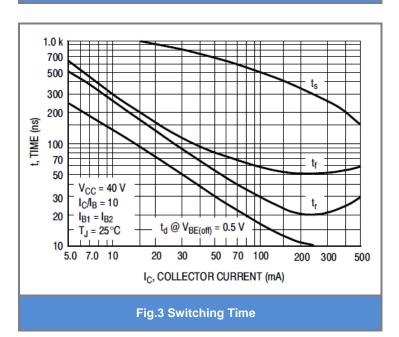
Electrical Characteristics (T_A=25 °C unless otherwise noted)

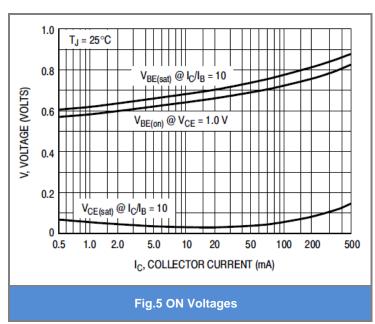
| PAR | AMETER | SYMBOL | MIN. | MAX. | UNITS |
|---|------------------|----------------------|------|------|---------|
| OFF Characteristics | | | | | |
| Collector-Emitter Breakdown Volta | age | | | | |
| $(I_C=1.0mA, I_B=0)$ | MMBTA05, MMBTA55 | $V_{(BR)CEO}$ | 60 | - | V |
| | MMBAT06, MMBTA56 | | 80 | - | |
| Emitter-Base Breakdown Voltage | | V | 4 | | V |
| $(I_E=100\mu A, I_C=0)$ | | $V_{(BR)EBO}$ | 4 | - | V |
| Collector Cutoff Current | | , | - | 0.1 | |
| $(V_{CE}=60V, I_{B}=0)$ | | I _{CES} | | | μА |
| Collector Cutoff Current | | | | | |
| $(V_{CB}=60V, I_{E}=0)$ | MMBTA05, MMBTA55 | I _{CBO} | - | 0.1 | μΑ |
| $(V_{CB}=80V, I_{E}=0)$ | MMBAT06, MMBTA56 | | - | 0.1 | |
| ON characteristics | | | | | |
| DC Current Gain | | | | | |
| $(I_C=10mA, V_{CE}=1V)$ | | f _{FE} | 100 | - | - |
| (I _C =100mA, V _{CE} =1V) | | | 100 | - | |
| Collector-Emitter Saturation Voltage | ge | | | | |
| (I _C =100mA, I _B =10mA) | | V _{CE(SAT)} | - | 0.25 | V |
| Base-Emitter On Voltage | | | | | |
| (I _C =100mA, V _{CE} =1V) | | $V_{BE(ON)}$ | - | 1.2 | V |
| Small-signal characteristics | | | | | |
| Current-Gain-Bandwidth Product | | | 100 | - | N 41 1_ |
| (I _C =10mA, V _{CE} =2V, f=100MHz) | | f⊤ | | | MHz |

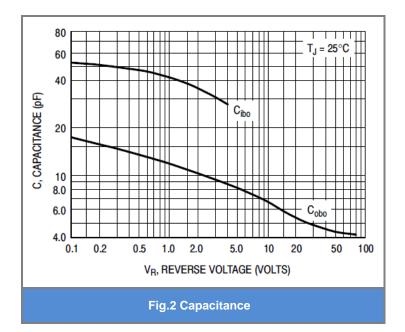


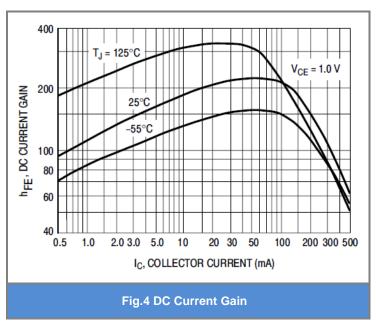


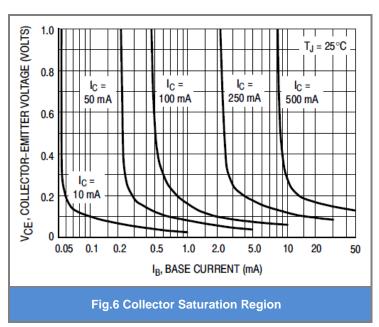
















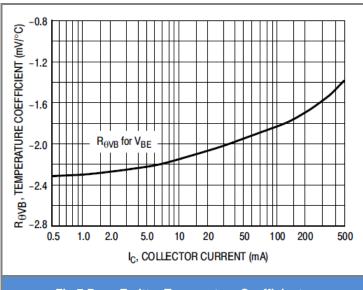


Fig.7 Base-Emitter Temperature Coefficient

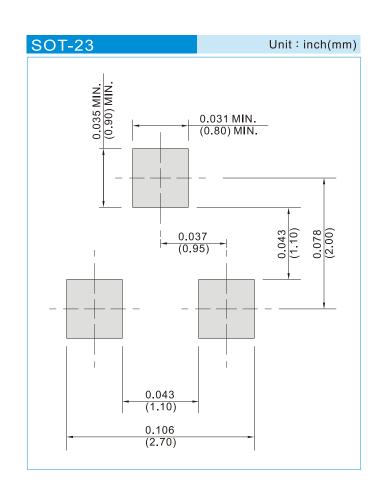




Part No Packing Code Version

| Part No Packing Code | Package Type Packing Type Markii | | Marking | Version | |
|----------------------|----------------------------------|----------------|---------|--------------|--|
| MMBTA05_R1_00001 | SOT-23 | 3K / 7" Reel | B05 | Halogen Free | |
| MMBTA05_R2_00001 | SOT-23 | 12K / 13" Reel | B05 | Halogen Free | |

Mounting Pad Layout







Disclaimer

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation. Customers are responsible in comprehending the suitable use in particular applications. Panjit International Inc. makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.
- The products shown herein are not designed and authorized for equipments relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - BJT category:

Click to view products by Panjit manufacturer:

Other Similar products are found below:

619691C MCH4017-TL-H MMBT-2369-TR BC546/116 BC557/116 BSW67A NJVMJD148T4G NTE123AP-10 NTE153MCP NTE16

NTE195A NTE92 C4460 2N4401-A 2N6728 2SA1419T-TD-H 2SA2126-E 2SB1204S-TL-E 2SC2712S-GR,LF 2SC5488A-TL-H

2SD2150T100R SP000011176 2N2907A 2N3904-NS 2N5769 2SC2412KT146S 2SD1816S-TL-E CPH6501-TL-E MCH4021-TL-E

MJE340 US6T6TR NJL0281DG 732314D CPH3121-TL-E CPH6021-TL-H 873787E IMZ2AT108 UMX21NTR MCH6102-TL-E

NJL0302DG 2N3583 30A02MH-TL-E NSV40301MZ4T1G NTE13 NTE26 NTE282 NTE323 NTE350 NTE81 STX83003-AP